

GENERAL PURPOSE SILICON RECTIFIER

EM513 THRU EM518

VOLTAGE RANGE CURRENT 1600 **to** 2000 **Volts** 1.0 **Amopere**

FEATURES

- · High reverse voltage
- · Low forward voltage drop
- · Low reverse leakage
- · High forward surge current capability.
- High temperature soldering guaranteed: 260°C/10 seconds, 0.375" (9.5mm)lead length at 5 lbs (2.3kg) tension.

MECHANICAL DATA

- · Case: transfer molded plastic
- Epoxy: UL94V 0 rate flame retardant.
- Polarity: Color band denotes cathode end.
- Lead: Plated axial lead, solderable per MIL STD 202E method 208C
- Mounting position: Any
- Weight: 0.012 ounce, 0.33grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

- Ratings at 25°C ambient temperature unless otherwise specified
- Single phase, half wave, 60Hz, resistive or inductive load.
- For capacitive load derate current by 20%

	SYMBOLS	EM513	EM516	EM518	UNIT
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	1600	1800	2000	Volts
Maximum RMS Voltage	V_{RMS}	1120	1260	1400	Volts
Maximum DC Blocking Voltage	V_{DC}	1600	1800	2000	Volts
Maximum Average Forward Rectified Current, 0.375" (9.5mm) lead length at $T_A = 75^{\circ}C$	$I_{(AV)}$	1.0			Amp
Peak Forward Surge Current 8.3ms single half sine - wave superimposed on rated load (JEDEC method)	I_{FSM}	30			Amps
Maximum Instantaneous Forward Voltage at 1.0A	V_{F}	1.1 1.2		Volts	
Maximum DC Reverse Current at rated $T_A = 25^{\circ}C$ DC blocking voltage $T_A = 100^{\circ}C$	I _R	5.0 50			μ Α
Maximum Full Load Reverse Current, full cycle average 0.375" (9.5mm) lead length at $T_L = 75^{\circ}C$	$I_{R(AV)}$	30			μΑ
Typical Junction Capacitance (Note 1)	C_{J}	15			pF
Typical Thermal Resistance (Note2)	$R_{ heta JA}$	50			°C/W
Operating and Storage Temperature Range	T_{J}	(-65 to +175)			$^{\circ}\!\mathbb{C}$
Storage Temperature Range	T_{STG}	(-65 to +175)			$^{\circ}\!\mathbb{C}$

NOTES:

- 1. Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts.
- 2. Thermal Resistance from Junction to Ambient at 0.375" (9.5mm) lead length, P.C. board mounted.

FIG.1-TYPICAL FORWARD CURRENT

DERATING CURVE

1.2

1.0

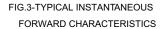
0.8

0.6

Single Phase
Half Wave 60Hz
Resistive or
Inductive Load
0.25

0.75 100 125 150 175

AMBIENT TEMPERATURE, (C)



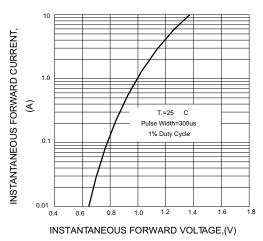
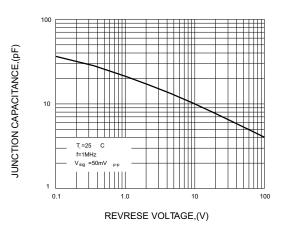
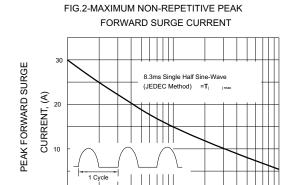


FIG.5-TYPICAL JUNCTION CAPACITANCE





6 8 10

NUMBER OF CYCLES AT 60 Hz

